

www.vishay.com

Vishay Semiconductors

## Schottky Rectifier, 2 x 10 A



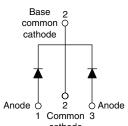
V<sub>F</sub> at I<sub>F</sub>

I<sub>RM</sub> max.

T<sub>J</sub> max.

Diode variation

 $\mathsf{E}_{\mathsf{AS}}$ 



0.57 V

15 mA at 125 °C

150 °C

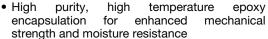
Common cathode

8 mJ

TO-220AB	Anode 0 2 O Anode 1 Common 3 cathode
PRODUCT SUMMARY	
Package	TO-220AB
I <sub>F(AV)</sub>	2 x 10 A
$V_{R}$	35 V, 45 V

#### **FEATURES**

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

#### **DESCRIPTION**

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	SYMBOL CHARACTERISTICS VALUES UNI								
I <sub>F(AV)</sub>	Rectangular waveform (per device)	20	Α						
V <sub>RRM</sub>		35/45	V						
I <sub>FRM</sub>	T <sub>C</sub> = 135 °C (per leg)	20							
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	1060	A						
V <sub>F</sub>	10 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.57	V						
TJ	Range	- 65 to 150	°C						

VOLTAGE RATINGS									
PARAMETER	SYMBOL	VS-MBR2035CTPbF	VS-MBR2035CT-N3	VS-MBR2045CTPbF	VS-MBR2045CT-N3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	35	35	45	45	V			
Maximum working peak reverse voltage	$V_{RWM}$	33	33	43	43	V			

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	PARAMETER SYMBOL TEST CONDITIONS		CONDITIONS	VALUES	UNITS		
Maximum average per leg	I	T 135 °C rated V-		10			
forward current per device	I <sub>F(AV)</sub>	IC = 133 O, Taled VR	$T_C = 135$ °C, rated $V_R$				
Peak repetitive forward current per leg	I <sub>FRM</sub>	Rated V <sub>R</sub> , square wave, 20	kHz, T <sub>C</sub> = 135 °C	20			
Non-repetitive peak surge current	I <sub>FSM</sub> .	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V <sub>RRM</sub> applied	1060	Α		
		Surge applied at rated load condition half wave, single phase, 60 Hz		150			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by $T_J$ maximum $V_A = 1.5 \ x \ V_R$ typical		2			
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 2 A, L = 4 mH		8	mJ		



www.vishay.com

# Vishay Semiconductors

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
		20 A	T <sub>J</sub> = 25 °C	0.84		
Maximum forward voltage drop	V <sub>FM</sub> <sup>(1)</sup>	10 A	T 405 00	0.57	V	
		20 A	T <sub>J</sub> = 125 °C	0.72		
Maximum instantaneous reverse current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	Rated DC voltage	0.1	mA	
Maximum instantaneous reverse current		T <sub>J</sub> = 125 °C	hated DC voltage	15		
Threshold voltage	V <sub>F(TO)</sub>	T. – T. maximum		0.354	٧	
Forward slope resistance	r <sub>t</sub>	rj = rj maximum	$T_J = T_J$ maximum			
Maximum junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 5 V <sub>DC</sub> (test signal ran	600	pF		
Typical series inductance	L <sub>S</sub>	Measured from top of term	8.0	nH		
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	Rated V <sub>R</sub> 10 000 V/ <sub>k</sub>			

#### Note

 $<sup>^{(1)}</sup>$  Pulse width < 300  $\mu$ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		BOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction temperature	range T	J		- 65 to 150	°C	
Maximum storage temperature r	ange T <sub>S</sub>	itg		- 65 to 175	- U	
Maximum thermal resistance, junction to case per leg		JC	DC operation	2.0	°C/W	
Typical thermal resistance, case to heatsink	R <sub>th</sub>	cs	Mounting surface, smooth and greased (only for TO-220)	0.50	C/VV	
Approximate weight				2	g	
Approximate weight				0.07	OZ.	
Mounting torque r	minimum		Non-lubricated threads	6 (5)	kgf · cm	
	naximum		Non-lubricated tilleads	12 (10)	(lbf · in)	
Marking device			Constitution TO 220AB	MBR2035CT		
		Case style TO-220AB		MBR2045CT		

www.vishay.com

Vishay Semiconductors

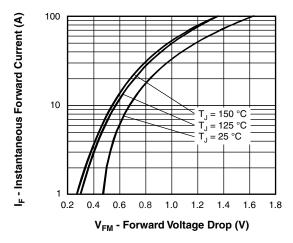


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

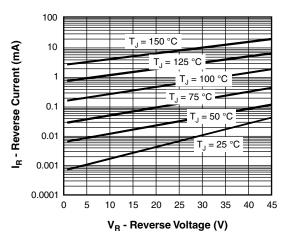


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

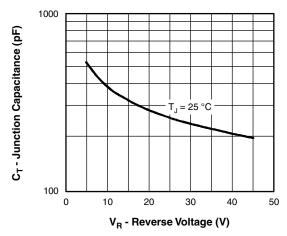


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

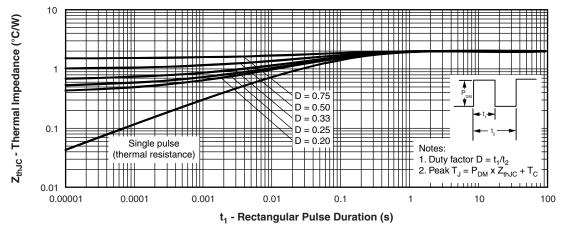


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

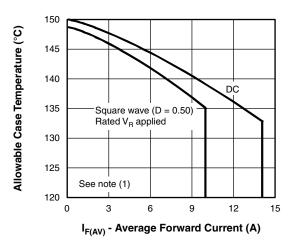


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

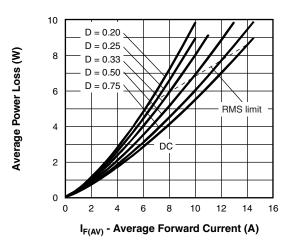


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

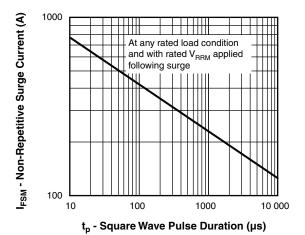


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

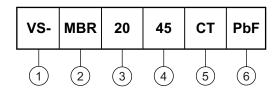
#### Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6)}; \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = \text{Rated } V_R \\ \end{array}$ 

Vishay Semiconductors

### **ORDERING INFORMATION TABLE**

**Device code** 



Vishay Semiconductors product

2 - Schottky MBR series

- Current rating (20 = 20 A)

35 = 35 V 45 = 45 V

CT = Essential part number

6 - Environmental digit

• PbF = Lead (Pb)-free and RoHS compliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBR2035CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2035CT-N3	50	1000	Antistatic plastic tube				
VS-MBR2045CTPbF	50	1000	Antistatic plastic tube				
VS-MBR2045CT-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95222				
Dout moulting information	TO-220AB PbF	www.vishay.com/doc?95225				
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028				
SPICE model		www.vishay.com/doc?95295				



### Vishay Semiconductors

### **TO-220AB**

#### **DIMENSIONS** in millimeters and inches



### Lead assignments

#### **Diodes**

- 1. Anode/open
- 2. Cathode
- 3. Anode

#### Conforms to JEDEC outline TO-220AB

SYMBOL	MILLIN	IETERS	INC	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

SYMBOL	MILLIM	IETERS	INC	HES	NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
E2	-	0.76	-	0.030	7
е	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6, 7
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØΡ	3.54	3.73	0.139	0.147	
Q	2.60	3.00	0.102	0.118	
θ	90° to 93°		90° t	o 93°	
		•	•	•	

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline

Lead tip



### **Legal Disclaimer Notice**

Vishay

### **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and/or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk and agree to fully indemnify and hold Vishay and its distributors harmless from and against any and all claims, liabilities, expenses and damages arising or resulting in connection with such use or sale, including attorneys fees, even if such claim alleges that Vishay or its distributor was negligent regarding the design or manufacture of the part. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

# **Material Category Policy**

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

# **Mouser Electronics**

**Authorized Distributor** 

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

### Vishay:

<u>MBR2035CT MBR2045CT MBR2080CTKPBF MBR2090CTKPBF MBR2035CT/45 MBR2045CT/45 MBR2045CT-</u>
<u>E3/45 VS-MBR2045CTPBF</u>